



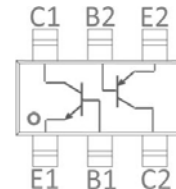
## Features

- Complementary Pair.
- One 3904-Type NPN.
- One 3906-Type PNP.
- Epitaxial Planar Die Construction.
- Ideal for Low Power Amplification and Switching.



Pin 1

SOT-363



Pin 1

## Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HMMDT39467F	SOT-363	K46	3000

## Maxmim Ratings (Ta=25 unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	60	V
$V_{CEO}$	Collector-Emitter Voltage	40	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current	200	mA
$P_C$	Collector Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	625	°C/W
$T_J, T_{stg}$	Operation Junction And Storage Temperature Range	-55~+150	°C

## NPN 3904 Electrcal Charcteristics (Ta=25 unless otherwise noted)

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$V_{(BR)CBO}$	Collector-base breakdown voltage	$I_C=10\mu A, I_E=0$	60			V
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C=1mA, I_B=0$	40			V
$V_{(BR)EBO}$	Emitter-base breakdown voltage	$I_E=10\mu A, I_C=0$	5			V
$I_{CEO}$	Collector cut-off current	$V_{CE}=30V, I_B=0$			50	nA
$I_{CBO}$	Collector cut-off current	$V_{CB}=30V, I_E=0$			50	nA
$I_{EBO}$	Emitter cut-off current	$V_{EB}=5V, I_C=0$			50	nA
$h_{FE(1)}$	DC current gain(1)	$V_{CE}=1V, I_C=100\mu A$	40			
$h_{FE(2)}$	DC current gain(2)	$V_{CE}=1V, I_C=1mA$	70			
$h_{FE(3)}$	DC current gain(3)	$V_{CE}=1V, I_C=10mA$	100		300	
$h_{FE(4)}$	DC current gain(4)	$V_{CE}=1V, I_C=50mA$	60			
$h_{FE(5)}$	DC current gain(5)	$V_{CE}=1V, I_C=100mA$	30			
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_C=10mA, I_B=1mA$			0.2	V
		$I_C=50mA, I_B=5mA$			0.3	V
$V_{BE(sat)}$	Base-emitter saturation voltage	$I_C=10mA, I_B=1mA$	0.65		0.85	V
		$I_C=50mA, I_B=5mA$			0.95	V
$f_T$	Transition frequency	$V_{CE}=20V, I_C=10mA, f=100MHz$	300			MHz
$C_{ob}$	Collector output capacitance	$V_{CB}=5V, I_E=0, f=1MHz$			4	pF
NF	Noise figure	$V_{CE}=5V, I_C=0.1mA, f=1kHz, R_g=1K\Omega$			5	dB
$t_d$	Delay time	$V_{CC}=3V, V_{BE(off)}=0.5V, I_C=10mA, I_{B1}=I_{B2}=1mA$			35	ns
$t_r$	Rise time				35	ns
$t_s$	Storage time	$V_{CC}=3V, I_C=10mA, I_{B1}=I_{B2}=1mA$			225	ns
$t_f$	Fall time				75	ns



### Maxmim Ratings (Ta=25 unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-40	V
$V_{CEO}$	Collector-Emitter Voltage	-40	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current	-200	mA
$P_C$	Collector Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	625	°C/W
$T_J, T_{stg}$	Operation Junction And Storage Temperature Range	-55~+150	°C

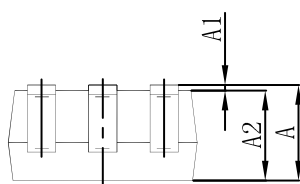
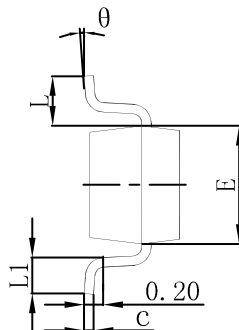
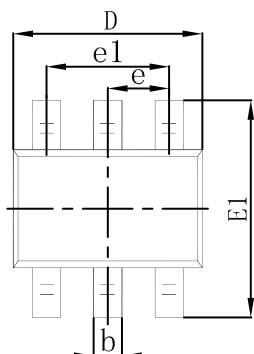
### PNP 3906 Electrcal Characteristics (Ta=25 unless otherwise noted)

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
$V_{(BR)CBO}^*$	Collector-base breakdown voltage	$I_C=-10\mu A, I_E=0$	-40			V
$V_{(BR)CEO}^*$	Collector-emitter breakdown voltage	$I_C=-1mA, I_B=0$	-40			V
$V_{(BR)EBO}^*$	Emitter-base breakdown voltage	$I_E=-10\mu A, I_C=0$	-5			V
$I_{CEX}^*$	Collector cut-off current	$V_{CE}=-30V, V_{EB(off)}=-3V$			-50	nA
$I_{CBO}$	Collector cut-off current	$V_{CB}=-30V, I_E=0$			-50	nA
$I_{EBO}$	Base cut-off current	$V_{EB}=-5V, I_E=0$			-50	nA
$h_{FE(1)}^*$	DC current gain(1)	$V_{CE}=-1V, I_C=-100\mu A$	60			
$h_{FE(2)}^*$	DC current gain(2)	$V_{CE}=-1V, I_C=-1mA$	80			
$h_{FE(3)}^*$	DC current gain(3)	$V_{CE}=-1V, I_C=-10mA$	100		300	
$h_{FE(4)}^*$	DC current gain(4)	$V_{CE}=-1V, I_C=-50mA$	60			
$h_{FE(5)}^*$	DC current gain(5)	$V_{CE}=-1V, I_C=-100mA$	30			
$V_{CE(sat)}^*$	Collector-emitter saturation voltage	$I_C=-10mA, I_B=-1mA$			-0.25	V
		$I_C=-50mA, I_B=-5mA$			-0.4	V
$V_{BE(sat)}^*$	Base-emitter saturation voltage	$I_C=-10mA, I_B=-1mA$	-0.65		-0.85	V
		$I_C=-50mA, I_B=-5mA$			-0.95	V
$f_T$	Transition frequency	$V_{CE}=-20V, I_C=-10mA, f=100MHz$	250			MHz
$C_{ob}$	Collector output capacitance	$V_{CB}=-5V, I_E=0, f=1MHz$			4.5	pF
NF	Noise figure	$V_{CE}=-5V, I_C=-0.1mA, f=1kHz, R_g=1K\Omega$			4	dB
$t_d$	Delay time	$V_{CC}=-3V, V_{BE(off)}=-0.5V,$ $I_C=-10mA, I_{B1}=I_{B2}=-1mA$			35	ns
$t_r$	Rise time				35	ns
$t_s$	Storage time	$V_{CC}=-3V, I_C=-10mA,$ $I_{B1}=I_{B2}=-1mA$			225	ns
$t_f$	Fall time				75	ns

\*Pulse test: pulse width  $\leq 300\mu s$ , duty cycles  $\leq 2.0\%$ .

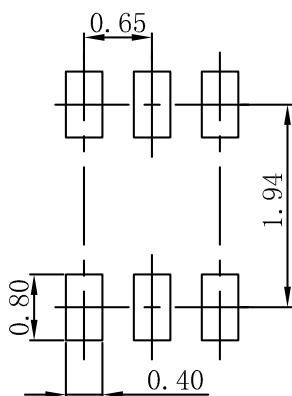


## SOT-363 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.100	0.150	0.004	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.400	0.085	0.094
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
theta	0°	8°	0°	8°

## SOT-363 Suggested Pad Layout



### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.



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